

# Standard specifications of 100mm Sn-doped $\beta$ -Ga<sub>2</sub>O<sub>3</sub> (001) substrate

Items		Specifications
Orientation		(001)
Dopant		Sn
Conductivity		n-type
Nd-Na (cm <sup>-3</sup> )		1×10 <sup>18</sup> ~ 2×10 <sup>19</sup>
Dimensions	Diameter (mm)	100 ±0.5
	Orientation flat width (mm)	32.5 ±2.5
	Index flat width (mm)	18.0 ±2.5
	Thickness (mm)	0.65 ±0.02
	Reference	Fig. 1
Offset angle (degree)	[010]:	0 ±1
	[100]:	0 ±1
FWHM (arcsec)	[010]:	350 or less
	[100]:	350 or less
Surface	Front	CMP
	Back	CMP

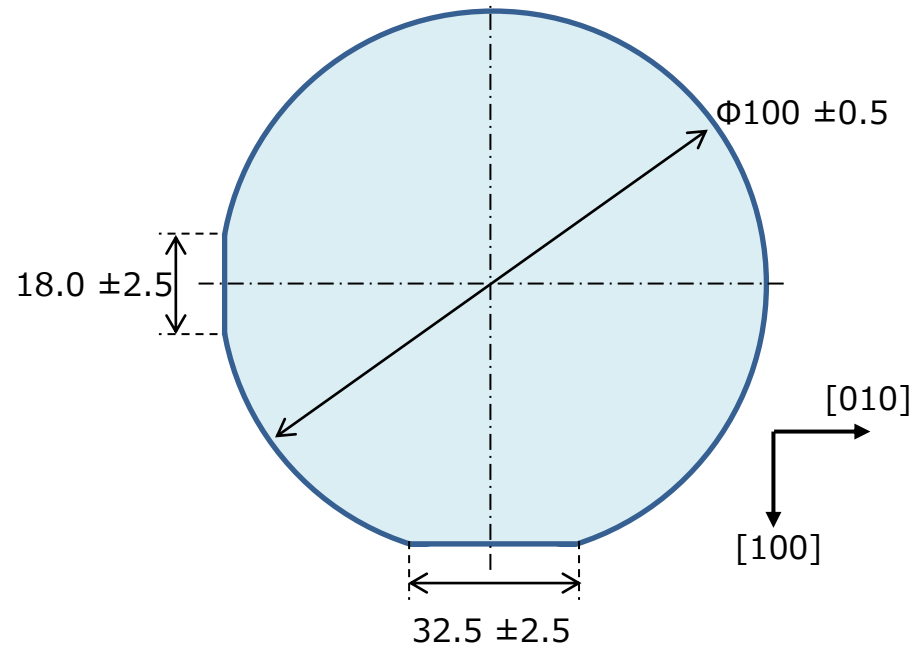


Fig. 1



Remarks

- 1 There are cases in which the other side of OF is chipped (a maximum of around IF width).
- 2 These products must be used for research and development purposes only.
- 3 The substrates must not be used as a seed crystal.
- 4 The specifications are subject to change without notice.

# Standard specifications of 2 inch Sn-doped $\beta$ -Ga<sub>2</sub>O<sub>3</sub> (001) substrate

Items		Specifications
Orientation		(001)
Dopant		Sn
Conductivity		n-type
$N_d-N_a$ (cm <sup>-3</sup> )		$1 \times 10^{18} \sim 2 \times 10^{19}$
Dimensions	Diameter (mm)	$50.8 \pm 0.3$
	Orientation flat width (mm)	$15.9 \pm 2.5$
	Index flat width (mm)	$8.0 \pm 2.5$
	Thickness (mm)	$0.65 \pm 0.02$
	Reference	Fig. 2
Offset angle (degree)	[010]:	$0 \pm 1$
	[100]:	$0 \pm 1$
FWHM (arcsec)	[010]:	350 or less
	[100]:	350 or less
Surface	Front	CMP
	Back	CMP

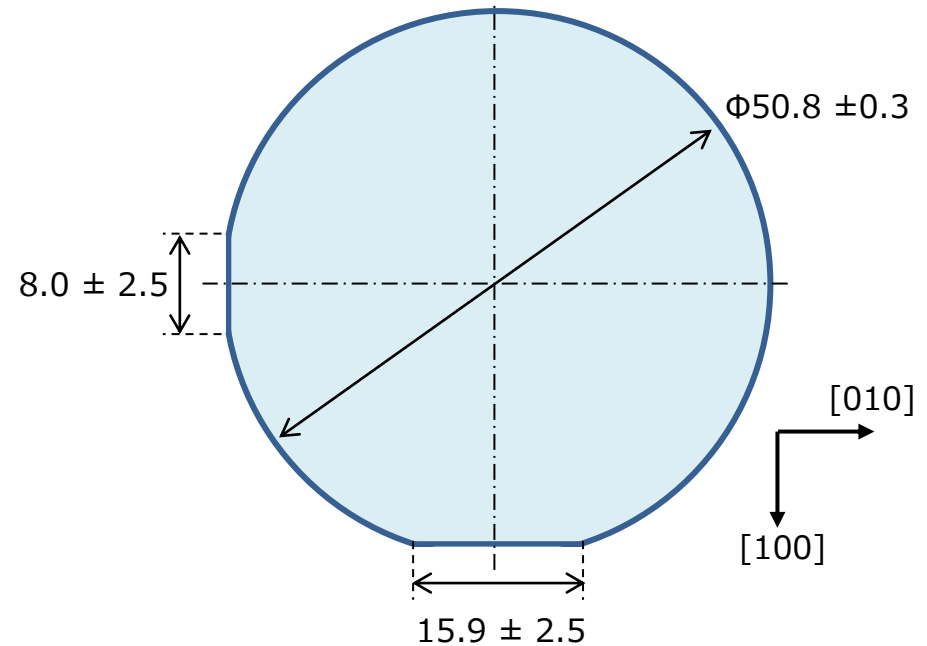


Fig.2

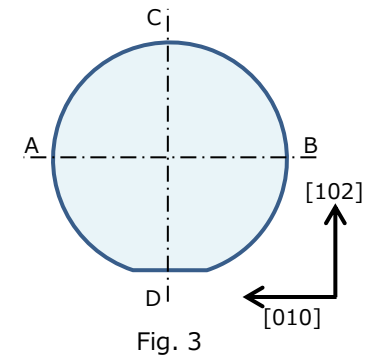


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# Standard specifications of 2 inch $\beta$ -Ga<sub>2</sub>O<sub>3</sub> ( $\bar{2}01$ ) substrates

Items		Specifications		
Orientation		$(\bar{2}01)$		
Dopant		Sn	Undoped	Fe
Conductivity		n-type	n-type	Insulating ( $> 10^{10}\Omega \cdot \text{cm}$ )
$N_d-N_a$ (cm <sup>-3</sup> )		$1 \times 10^{18} \sim 9 \times 10^{18}$	$\leq 9 \times 10^{17}$	-
Dimensions	A-B (mm)	$50.8 \pm 0.3$	$50.8 \pm 0.3$	$50.8 \pm 0.3$
	C-D (mm)	$49.5 \pm 0.3$	$49.5 \pm 0.3$	$49.5 \pm 0.3$
	Thickness (mm)	$0.68 \pm 0.02$	$0.68 \pm 0.02$	$0.68 \pm 0.02$
	Reference	Fig. 3	Fig. 3	Fig. 3
Offset angle (degree)		[010]: $0 \pm 0.4$	[010]: $0 \pm 0.4$	[010]: $0 \pm 1$
		[102]: $-0.7 \pm 0.4$	[102]: $-0.7 \pm 0.4$	[102]: $-0.7 \pm 1$
FWHM (arcsec)		[010]: 150 or less	[010]: 150 or less	[010]: 150 or less
		[102]: 150 or less	[102]: 150 or less	[102]: 150 or less
Surface	Front	CMP	CMP	CMP
	Back	Grinding	Grinding	Grinding



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# Standard specifications of 10x15 mm<sup>2</sup> β-Ga<sub>2</sub>O<sub>3</sub> substrates

Items		Specifications					
Orientation		$(\bar{2}01)$			$(010)$		
Dopant		Sn	Undoped	Fe	Sn	Undoped	Fe
Conductivity		n-type	n-type	Insulating ( $> 10^{10}\Omega \cdot \text{cm}$ )	n-type	n-type	Insulating ( $> 10^{10}\Omega \cdot \text{cm}$ )
Na-Na (cm <sup>-3</sup> )		$1 \times 10^{18} \sim 9 \times 10^{18}$	$\leq 9 \times 10^{17}$	-	$1 \times 10^{18} \sim 9 \times 10^{18}$	$\leq 9 \times 10^{17}$	-
Dimensions	A-B (mm)	15 ±0.3	15 ±0.3	15 ±0.3	15 ±0.3	15 ±0.3	15 ±0.3
	C-D (mm)	10 ±0.3	10 ±0.3	10 ±0.3	10 ±0.3	10 ±0.3	10 ±0.3
	Thickness (mm)	0.68 ±0.02	0.68 ±0.02	0.68 ±0.02	0.5 ±0.02	0.5 ±0.02	0.5 ±0.02
	Reference	Fig. 4	Fig. 4	Fig. 4	Fig. 5	Fig. 5	Fig. 5
Offset angle (degree)	[010]: 0 ±0.4	[010]: 0 ±0.4	[010]: 0 ±1	⊥[102]: 0 ±1	⊥[102]: 0 ±1	⊥[102]: 0 ±1	
	[102]: -0.7 ±0.4	[102]: -0.7 ±0.4	[102]: -0.7 ±1	[102]: 0 ±1	[102]: 0 ±1	[102]: 0 ±1	
FWHM (arcsec)	[010]: 150 or less	[010]: 150 or less	[010]: 150 or less	⊥[102]: 150 or less	⊥[102]: 150 or less	⊥[102]: 150 or less	
	[102]: 150 or less	[102]: 150 or less	[102]: 150 or less	[102]: 150 or less	[102]: 150 or less	[102]: 150 or less	
Surface	Front	CMP	CMP	CMP	CMP	CMP	CMP
	Back	Grinding	Grinding	Grinding	Grinding	Grinding	Grinding

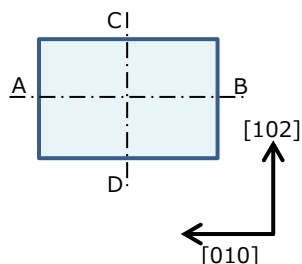


Fig. 4

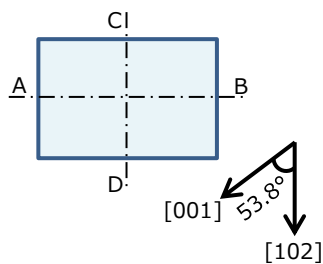


Fig. 5

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# Standard specifications of 10x15 mm<sup>2</sup> $\beta$ -Ga<sub>2</sub>O<sub>3</sub> substrates

Items		Specifications		
Orientation		(001)		
Dopant		Sn	Undoped	Fe
Conductivity		n-type	n-type	Insulating ( $> 10^{10}\Omega \cdot \text{cm}$ )
$N_d-N_a$ (cm <sup>-3</sup> )		$1 \times 10^{18} \sim 2 \times 10^{19}$	$\leq 9 \times 10^{17}$	-
Dimensions	A-B (mm)	15 $\pm$ 0.3	15 $\pm$ 0.3	15 $\pm$ 0.3
	C-D (mm)	10 $\pm$ 0.3	10 $\pm$ 0.3	10 $\pm$ 0.3
	Thickness (mm)	0.65 $\pm$ 0.02	0.65 $\pm$ 0.02	0.65 $\pm$ 0.02
	Reference	Fig. 5	Fig. 5	Fig. 5
Offset angle (degree)		[010]:0 $\pm$ 1	[010]:0 $\pm$ 1	[010]:0 $\pm$ 1
		[100]:0 $\pm$ 1	[100]:0 $\pm$ 1	[100]:0 $\pm$ 1
FWHM (arcsec)		[010]:150 or less	[010]:150 or less	[010]:150 or less
		[100]:150 or less	[100]:150 or less	[100]:150 or less
Surface	Front	CMP	CMP	CMP
	Back	CMP	Grinding	Grinding

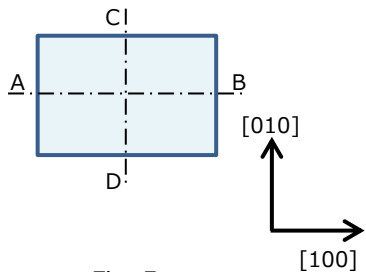


Fig. 5

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**Novel Crystal Technology, Inc.**